

Description

The BPT-HP233-TRB is a silicon NPN phototransistor detector in a 3.2x1.6x1.1mm SMD type package.

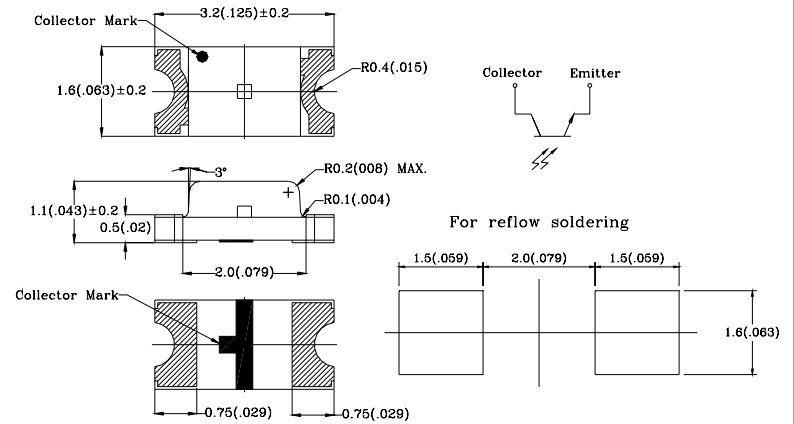
Features:

1. Wide range of collector current.
2. Lend for high sensitivity.
3. Low cost plastic package.
4. Lens Appearance: Water Clear
5. This product doesn't contain restriction Substance, comply ROHS standard.

Applications:

1. Smoke Detector
2. Automatic Control System
3. Any design requiring sensitivity and stable characteristics.

Package Dimensions:



NOTES:

1. All dimensions are in millimeters (inches).
2. Tolerance is ±0.10mm (0.004") unless otherwise specified.
3. Specifications are subject to change without notice.

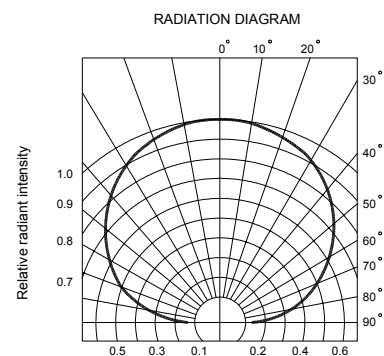
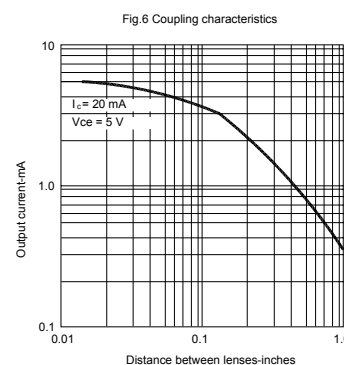
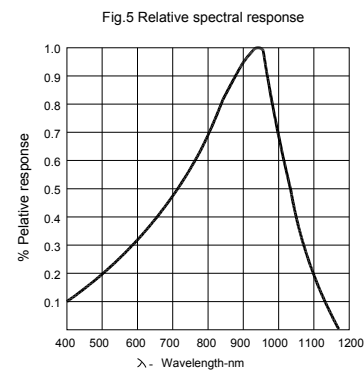
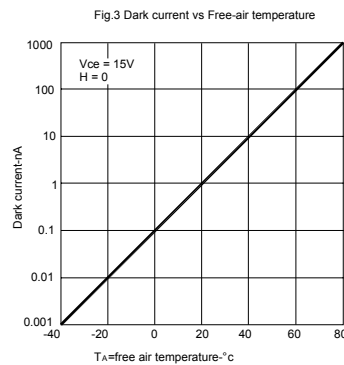
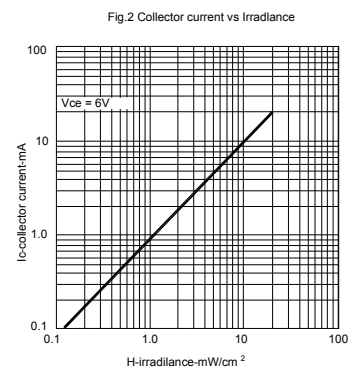
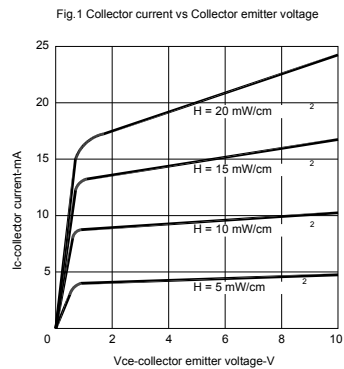
Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Rating	Unit
Power Dissipation	Pd	100	mW
Emitter-Collector Breakdown Voltage	BV _{CEO}	30	
Emitter-Collector Voltage	BV _{ECO}	5	V
Operating Temperature	Topr	-40°C~85°C	-
Storage Temperature	Tstg	-40°C~85°C	-
Soldering Temperature	Tsol	See Page6	-

● Electrical and optical characteristics(Ta=25°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Spectrum Sensitivity	λ	$I_F=50\text{mA}$	500	-	1000	nm
Short Circuit Current	λp	$I_F=50\text{mA}$	-	940	-	nm
Collector Light Current	$I_{C(ON)}$	$V_{CE}=5\text{V}$, $\lambda p=940\text{nm}$, $H=1.0\text{mw/cm}^2$	2.398	4.977	-	mA
Collector Dark Current	I_{CEO}	$V_{CE}=20\text{V}$	-	-	100	nA
Rise/Fall Time	T_r/T_f	$V_{CE}=5\text{V}$, $I_c=1\text{mA}$, $R_L=1\text{K}\Omega$	-	15/15	-	us
viewing Angle	$2\theta_{1/2}$	$I_F=50\text{mA}$	-	140	-	deg

● Typical Electro-Optical Characteristics Curves



● Bin Limits:

Collector Light Current Bin Limits($V_{CE}=5V$, $H=1.0\text{mw/cm}^2$, $\lambda_p=940\text{nm}$)

BIN CODE	$I_{C(ON)}$ (mA)	
	Min	Max
M	2.398	3.455
N	3.455	4.977
P	4.977	7.165
Q	7.165	10.319

Tolerance for each Bin limit is $\pm 15\%$.

● BIN : X



Collector Light Current Bin Code

● Reliability Test

Classification	Test Item	Reference Standard	Test Conditions	Result
Endurance Test	Operation Life	MIL-STD-750D:1026 MIL-STD-883D:1005 JIS-C-7021 :B-1	Connect with a power $V_{CE}=5V$ T_a =Under room temperature Test time=1,000hrs	0/20
	High Temperature High Humidity Storage	MIL-STD-202F:103B JIS-C-7021 :B-11	$T_a=+85^{\circ}C \pm 5^{\circ}C$ RH=90%-95% Test time=240hrs	0/20
	High Temperature Storage	MIL-STD-883:1008 JIS-C-7021 :B-10	High $T_a=+100^{\circ}C \pm 5^{\circ}C$ Test time=1,000hrs	0/20
	Low Temperature Storage	JIS-C-7021 :B-11	Low $T_a=-40^{\circ}C \pm 5^{\circ}C$ Test time=1,000hrs	0/20
Environmental Test	Temperature Cycling	MIL-STD-202F:107D MIL-STD-750D:1051 MIL-STD-883D:1010 JIS-C-7021 :A-2	$-35^{\circ}C \pm 5^{\circ}C \sim +25^{\circ}C \sim +85^{\circ}C \pm 5^{\circ}C \sim +25^{\circ}C$ 30min 5min 30min 5min Test Time=10cycle	0/20
	Thermal Shock	MIL-STD-202F:107D MIL-STD-750D:1051 MIL-STD-883D:1011	$-40^{\circ}C \pm 5^{\circ}C \sim +85^{\circ}C \pm 5^{\circ}C$ 20min 20min Test Time=10cycle	0/20
	Solder Resistance	MIL-STD-202:201A MIL-STD-750:2031 JIS-C-7021 :A-1	Preheating : 140°C-160°C, within 2 minutes. Operation heating : 260°C (Max.), within 10seconds. (Max.)	0/20

● Judgment criteria of failure for the reliability

Measuring items	Symbol	Measuring conditions	Judgment criteria for failure
Collector Dark Current	I_{CEO}	$V_{CE}=20V$	Over $U*2$
Collector Light Current	$I_{C(ON)}$	$V_{CE}=5V$, $H=1.0 \text{ mW/cm}^2$, $\lambda_p=940\text{nm}$	Initial Level*0.7

Note: 1.U means the upper limit of specified characteristics.

2.Measurment shall be taken between 2 hours and after the test pieces have been returned to normal ambient conditions after completion of each test.

● Soldering:

1. Manual Of Soldering

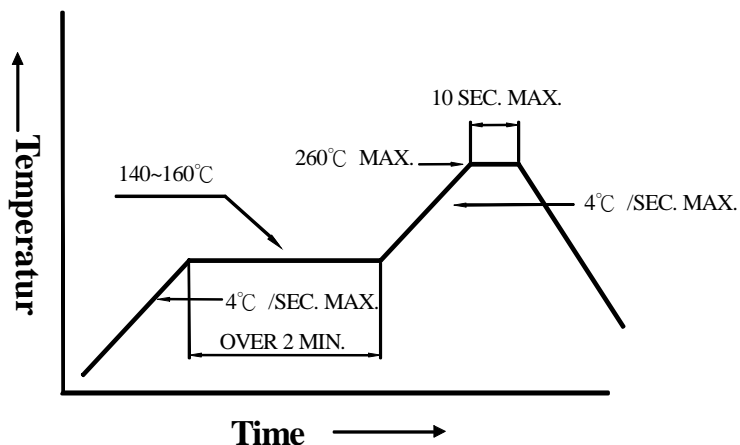
The temperature of the iron tip should not be higher than 300°C (572°F) and Soldering within 3 seconds per solder-land is to be observed.

2. Reflow Soldering

Preheating : 140°C~160°C ±5°C, within 2 minutes.

Operation heating : 260°C (Max.) within 10 seconds.(Max)

Gradual Cooling (Avoid quenching).

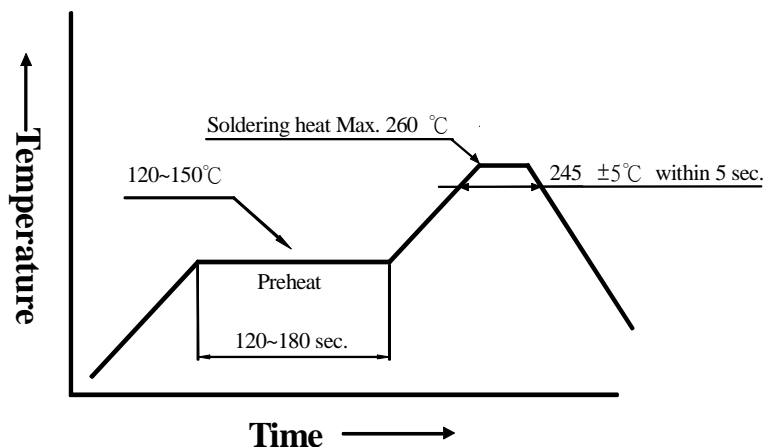


3. DIP soldering (Wave Soldering) :

Preheating : 120°C~150°C, within 120~180 sec.

Operation heating : 245°C ±5°C within 5 sec. 260°C (Max)

Gradual Cooling (Avoid quenching).



● Handling :

Care must be taken not to cause to the epoxy resin portion of BRIGHT LEDs while it is exposed to high temperature.

Care must be taken not rub the epoxy resin portion of BRIGHT LEDs with hard or sharp article such as the sand blast and the metal hook.

● Notes for designing:

Care must be taken to provide the current limiting resistor in the circuit so as to drive the BRIGHT LEDs within the rated figures. Also, caution should be taken not to overload BRIGHT LEDs with instantaneous voltage at the turning ON and OFF of the circuit.

When using the pulse drive care must be taken to keep the average current within the rated figures. Also, the circuit should be designed so as to be subjected to reverse voltage when turning off the BRIGHT LEDs.

● Storage:

In order to avoid the absorption of moisture, it is recommended to solder BRIGHT LEDs as soon as possible after unpacking the sealed envelope.

If the envelope is still packed, to store it in the environment as following:

- (1) Temperature : 5°C -30°C (41°F) Humidity : RH 60% Max.
- (2) After this bag is opened, devices that will be applied to infrared reflow, vapor-phase reflow, or equivalent soldering process must be:
 - a. Completed within 168 hours.
 - b. Stored at less than 30% RH.
- (3) Devices require baking before mounting, if:
 - (2) a or (2) b is not met.
- (4) If baking is required, devices must be baked under below conditions:
48 hours at 60°C±3°C.

● Package and Label of Products:

- (1) Package: Products are packed in one bag of 3000 pcs (one taping reel) and a label is attached on each bag.
- (2) Label:

